2SD1938(F)

Silicon NPN epitaxial planar type

For low-voltage output amplification For muting

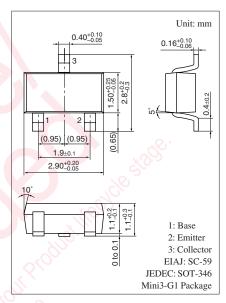
For DC-DC converter

■ Features

- Low ON resistance Ron
- High forward current transfer ratio h_{FE}
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing

■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V_{CBO}	50	V	
Collector-emitter voltage (Base open)	V_{CEO}	20	V	
Emitter-base voltage (Collector open)	$V_{\rm EBO}$	25	V	
Collector current	I_{C}	300	mA	
Peak collector current	I_{CP}	500	mA	
Collector power dissipation	P _C	200	mW	
Junction temperature	T_{j}	150	°C	
Storage temperature	T_{stg}	-55 to +150	P °C	



Marking symbol: 3W

■ Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

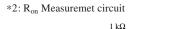
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = 1 \text{ mA}, I_B = 0$	20			V
Base-emitter voltage	V_{BE}	$V_{CE} = 2 \text{ V}, I_C = 4 \text{ mA}$	10 J	0.6		V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 50 \text{ V}, I_E = 0$	7.7		0.1	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 25 \text{ V}, I_C = 0$			0.1	μΑ
Forward current transfer ratio *1	h _{FE}	$V_{CE} = 2 \text{ V}, I_C = 4 \text{ mA}$	500		2500	_
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$			0.1	V
Transition frequency	f_T	$V_{CB} = 6 \text{ V}, I_E = -4 \text{ mA}, f = 200 \text{ MHz}$		80		MHz
Collector output capacitance	C _{ob}	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$			7	pF
(Common base, input open circuited)		216,02 Night				
ON resistance *2	Ron	- Control of the cont		1.0		Ω

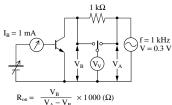
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

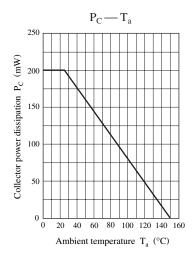
2. *1: Rank classification

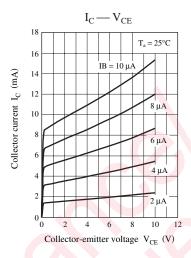
Rank	S	Т	No rank	
h_{FE}	500 to 1 500	800 to 2500	500 to 2500	

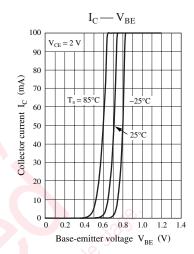
Product of no-rank classification is not marked.

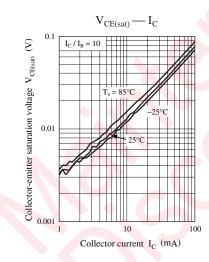


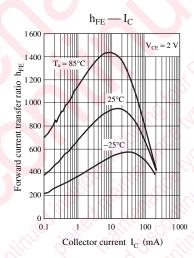


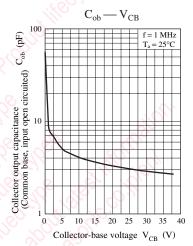












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